Compositional Asymmetric Tri-Color Superlattices Grown by Pulsed Laser Deposition

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ABSTRACT

Compositionally asymmetric tri-color superlattices (TCS) with a combination of BaTiO$_3$/SrTiO$_3$/CaTiO$_3$ have been grown by pulsed laser deposition (PLD) on atomically-flat SrRuO$_3$-covered (001) SrTiO$_3$ substrates. Conducting SrRuO$_3$ films with single-terrace steps that closely mimic those of the SrTiO$_3$ substrate also were grown by PLD and serve as bottom electrodes. In order to achieve atomic control of each layer, we have calibrated precisely the number of laser pulses required to grow one unit-cell-thick layers (~200 for a laser spot of 0.4 mm$^2$). These conditions allowed recording of pronounced oscillations of the reflection high-energy electron diffraction (RHEED) specular spot intensity over the entire growth run - even for TCS layers totaling more than 1000 nm in total thickness.

INTRODUCTION

Advances in modern epitaxial growth techniques have enabled the growth of nearly perfect thin films, superlattices, etc. by the atomic-scale control of surfaces and interfaces. For instance, oxide heterostructures with atomically-flat interfaces and single unit-cell steps on the surface can be grown on well-prepared single-stepped substrates. Moreover, artificial superlattices – i.e., materials that do not exist in bulk forms – can be grown with great control on such substrates and are expected to result in unprecedented physical properties. Epitaxial thin films with arbitrary (but precisely controlled) stacking of layers with an A/B/C/…A/B/C geometry - so called tri-color or three-component superlattices (TCS), cf. Fig. 1 - can exhibit compositionally-broken inversion symmetry (CBIS), which results in strong self-poling due to the ionic size and/or electrostatic interaction effects by the isovalent and heterovalent substitutions, respectively [1]. Consequently, TCSs with CBIS may result in anomalous piezoelectricity and dielectric responses, and will allow a wide tunability of ferroelectric properties [2]. The growth of atomically-flat layers, however, is not trivial due
to lattice misfit, different growth modes, and lack of atomically-flat conducting layers for electric
correlation. For example, growing BaTiO$_3$ on SrTiO$_3$ (misfit ~2\%) involves the layer-then-
island growth mechanism which usually destroys the sharpness of subsequent interfaces if the
BaTiO$_3$ thickness exceeds two unit cells [3]. Thus, in order to design and fabricate functional
materials and structures thereof, it is paramount that systematic studies be carried out on the
growth behavior of transition metal oxides.

Here we report the growth control of TCSs consisting of BaTiO$_3$, SrTiO$_3$, and CaTiO$_3$ with
atomically flat interfaces and surfaces on SrRuO$_3$-coated SrTiO$_3$ substrates.

**EXPERIMENTS**

Before growing TCSs, SrRuO$_3$ films were grown by PLD on single-stepped (001) SrTiO$_3$
substrates (cf. Fig. 2a) using a KrF excimer laser ($\lambda = 248$ nm) at 700 °C in 100 mTorr O$_2$. The
single-stepped SrTiO$_3$ substrates were prepared by dipping as-purchased SrTiO$_3$ (miscut
tolerance < 0.1°) in NH$_4$F-buffered-HF (BHF) (pH=4.5, BHF: H$_2$O = 1:10) for 30–60 sec
followed by thermal anneal at 1100–1200 °C depending on the miscut angle of the substrates.
After characterizing the surface of SrRuO$_3$ films by atomic force microscopy (AFM) in air, the
samples were bonded onto a sample holder with Ag paint and reloaded in a different vacuum
chamber equipped with reflection high-energy electron diffraction (RHEED) for in-situ surface
monitoring. The TCSs were grown by PLD at ~700 °C in 10 mTorr of oxygen. The laser
repetition rate was varied from 1 to 20 Hz for the optimization phase and fixed finally at 5 Hz.
The laser fluence was fixed at 2 J/cm$^2$. The RHEED system was used at relatively high
background pressure (up to tens mTorr) by differential pumping the e-gun filament with a large
capacity turbo pump (pumping speed $\approx$ 300 l/s), which kept the pressure in the e-gun to less than
5×10$^{-6}$ Torr. Sintered stoichiometric CaTiO$_3$ and BaTiO$_3$ targets, and a single-crystal SrTiO$_3$
target were used for growing the TCSs. The orientation, crystallinity, and strain state of TCSs
were characterized by x-ray diffraction (XRD) $\theta$–2$\theta$ and two-axes (reciprocal space map) scans
using a PANalytical X’Pert MRD four-circle diffractometer.

**RESULTS AND DISCUSSION**

Atomically-flat, single-stepped SrTiO$_3$ substrates were prepared as described above.
Figure 2(a) shows a treated SrTiO$_3$ substrate used for growing SrRuO$_3$ thin films. The
corresponding AFM topographic image of the SrRuO$_3$ film [Fig. 2(b)] grown on the SrTiO$_3$
substrate also displays a nearly atomically-flat surface with uniform single steps. The terrace
widths are more or less identical to the SrTiO$_3$ substrate. We have not recorded RHEED
oscillations during SrRuO$_3$ growth due to the high pressure involved. Furthermore, RHEED
would yield limited information beyond a few monolayers of film deposition because the growth
mode at relatively high oxygen pressure quickly changes from layer-by-layer to step-flow [4].
The nearly atomically-flat surface of the SrRuO$_3$ film also is confirmed by the ex-situ RHEED image shown in Fig. 2(c). The RHEED image was taken along the <100> direction of SrRuO$_3$ and showed a very bright specular spot and diffraction spots, as well as the secondary Laue pattern, all revealing a high quality SrRuO$_3$ surface.

Since CaTiO$_3$ and SrTiO$_3$ both exhibit the layer-by-layer growth mode, and BaTiO$_3$, the layer-then-island growth mode, pronounced RHEED intensity oscillations were observed over the entire growth of CaTiO$_3$ and SrTiO$_3$, and at least few from BaTiO$_3$. This made it possible to calibrate accurately the number of laser pulses required to grow unit cells of CaTiO$_3$, SrTiO$_3$, and BaTiO$_3$ by counting the number of laser pulses necessary for one RHEED specular spot oscillation. Figure 3 shows how we have calibrated precisely the number of laser pulses. As shown in Fig. 3(a), apertures of different sizes were placed on a imaging beamline to achieve different laser spots (#1 = 7.7 mm$^2$, #2 = 2.0 mm$^2$, #3 = 1.1 mm$^2$, and #4 = 0.4 mm$^2$). Even with a small spot, the top edge of the laser plume reached the substrate surface. More importantly, small spots enable precise control of number of unit cells and highly consistent RHEED specular spot oscillations as shown in Fig. 3(b). In 0.4 mTorr O$_2$ background pressure, for instance, 19 laser pulses are required for growing one unit cell of SrTiO$_3$ when aperture #2 is used, whereas 148 laser pulses are required with aperture #4. At 10 mTorr, however, more laser pulses are needed due to increased collision and scattering of the ablated species [e.g., 190 laser pulses are needed for ~0.4 nm thick SrTiO$_3$ (1 u.c.)]. It turned out that growing with a larger aperture requires a reduction in laser repetition rate in order to allow enough migration time of species arriving on the substrate surface to nucleate before the successive species arrive. Under these conditions, the RHEED oscillation was pronounced, but layer coverage was difficult to control. Consequently, the smallest aperture (#4) was employed in order to control the layer thickness more precisely.

Artificial heterostructures, such as
TCSs, are possible on SrRuO$_3$ coated SrTiO$_3$ substrates. Figure 4 shows an example of a well-controlled TCS growth with pronounced RHEED specular spot oscillations and corresponding RHEED spots of a (BaTiO$_3$)$_1$/(CaTiO$_3$)$_3$/(SrTiO$_3$)$_3$ tri-color superlattice. It is worth noting that the TCSs have been grown at 10 mTorr O$_2$, which is one of highest oxygen pressures used for growing epitaxial titanates with precise control of the layer thickness by RHEED. Growing BaTiO$_3$ deteriorated the surface roughness and interface sharpness as confirmed by RHEED and transmission electron microscopy (not shown) due to the layer-then-island growth mode. Therefore, a “recovery process” is required in order to keep the overall superlattices flat and perfect on the atomic scale. This was achieved by depositing CaTiO$_3$ followed by SrTiO$_3$ with a well-controlled number of laser pulses for growing single or multiple unit cells, because CaTiO$_3$ and SrTiO$_3$ can be easily grown in the layer-by-layer fashion even on a relatively rough surface. The recovery process can be observed in Fig. 4(a). In addition, CaTiO$_3$ revealed a reconstruction feature as shown in Fig. 4(d), despite the otherwise similar behavior of CaTiO$_3$ and SrTiO$_3$. We attribute some of this difference to the use of a ceramic target for CaTiO$_3$. 

Figure 4. (a) RHEED intensity oscillation of the specular spot from a (BaTiO$_3$)$_1$/(CaTiO$_3$)$_3$/(SrTiO$_3$)$_3$ TCS showing a well-controlled surface of each layer. (b), (c), and (d) show RHEED spot images taken at the point I, II, and III, respectively, labeled in (a).

Figure 5. (a) XRD $\theta$-2$\theta$ scan and (b) reciprocal space map of a [(BaTiO$_3$)$_2$/(CaTiO$_3$)$_2$/(SrTiO$_3$)$_2$]$_{76}$ superlattice. The latter is recorded with the 114 reflection of SrTiO$_3$. The peaks due to remaining Cu-$K_{\beta}$ and W-$L_{\alpha}$ radiations from the substrate and the layer are labeled as (●) and (*), respectively. The peak labeled as (●) originated from Pt top electrodes. (c) AFM topography (5 x 5 $\mu$m$^2$) of the surface of the [(BaTiO$_3$)$_2$/(CaTiO$_3$)$_2$/(SrTiO$_3$)$_2$]$_{76}$ superlattice.
and a single-crystal for SrTiO₃, leading to the higher surface quality (and thus much brighter RHEED spot) for this layer.

X-ray diffraction $\theta$–$2\theta$ scan and reciprocal space map confirmed the high structural quality of superlattices. Figure 5(a) shows a $\theta$–$2\theta$ scan of a ~180 nm-thick TCS with a [(BaTiO₃)₂/(CaTiO₃)₂/(SrTiO₃)₂]₇₆ structure and Fig. 5(b) is a reciprocal space map [5] of the same sample recorded using the 114 reflection of SrTiO₃. Well-spaced superlattice-fringe peaks appear in both the $\theta$–$2\theta$ scan and the reciprocal space map. The latter also confirmed that the layers are fully strained (without relaxation). A typical AFM topography image – showing uniform terrace steps with a single unit cell height as shown in Fig. 5(c) – confirms the capability to grow nearly atomically-flat superlattices with complete reproducibility for hundreds of unit cells. TCSs could be grown with thicknesses in excess of one micron with pronounced RHEED oscillations and single-steps on the surface (not shown) if the thickness of BaTiO₃ was limited to less than three or four unit cells.

CONCLUSIONS

A-site isovalent artificial superlattices using CaTiO₃, SrTiO₃, and BaTiO₃ have been synthesized under precisely controlled growth conditions on single-stepped SrTiO₃ substrates covered with SrRuO₃ bottom electrodes. RHEED, AFM, and XRD investigations confirm the possibility of growing nearly atomically-flat superlattices with complete reproducibility for thousands of unit cells. Consequently, this work offers a proof-of-principle demonstration that attractive artificial structures and materials can be designed and developed for materials exploration with a view to revealing new physical properties.

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REFERENCES

5. An $\omega$-offset of about $-19.5^\circ$ was used for recording the reciprocal space map.